



NCE N-Channel Enhancement Mode Power MOSFET

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Description

The NCE8804 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications .It is ESD protested.

General Features

● V_{DS} = 20V,I_D =8A

 $R_{DS(ON)}$ < 19m Ω @ V_{GS} =2.5V

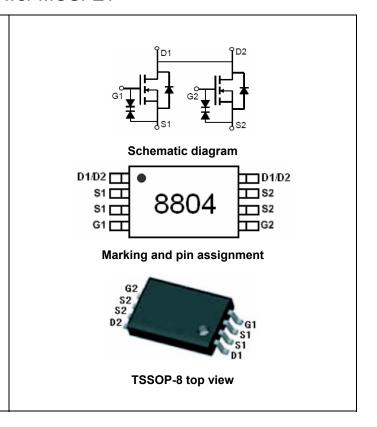
 $R_{DS(ON)}$ < 15m Ω @ V_{GS} =4.5V

ESD Rating: 2000V HBM

- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- Uni-directional load switch
- Bi-directional load switch



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
8804	NCE8804	TSSOP-8	Ø330mm	12mm	3000 units

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	20	V	
Gate-Source Voltage	V _{GS}	±12	V	
Drain Current-Continuous	I _D	8	Α	
Drain Current-Pulsed (Note 1)	I _{DM}	30	Α	
Maximum Power Dissipation	P _D	2	W	
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 150	$^{\circ}\!$	

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	62.5	°C/W
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Electrical Characteristics (T_A=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V,V _{GS} =0V	-	-	1	μA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±10V,V _{DS} =0V	-	-	±10	μA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_D=250\mu A$	0.45	0.7	1.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =5A	-	11	15	mΩ
Diain-Source On-State Resistance		V _{GS} =2.5V, I _D =4A	-	15	19	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =5A	-	15	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	V _{DS} =10V,V _{GS} =0V, F=1.0MHz	-	1800	-	PF
Output Capacitance	Coss		-	230	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0IVID2	-	200	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}	V_{DD} =10V, R_L =1.2 Ω	-	2.5		nS
Turn-on Rise Time	t _r		-	7.2		nS
Turn-Off Delay Time	$t_{\sf d(off)}$	V_{GS} =10 V , R_{GEN} =3 Ω	-	49		nS
Turn-Off Fall Time	t _f		-	10.8		nS
Total Gate Charge	Qg	V _{DS} =10V,I _D =8A, V _{GS} =4.5V	-	17.9		nC
Gate-Source Charge	Q _{gs}		-	1.5	-	nC
Gate-Drain Charge	Q_{gd}	v _{GS} -4.5 v	-	4.7	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =8A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	8	Α

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

Pb Free Product

Typical Electrical and Thermal Characteristics

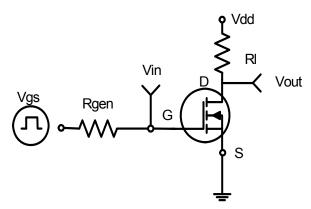


Figure 1:Switching Test Circuit

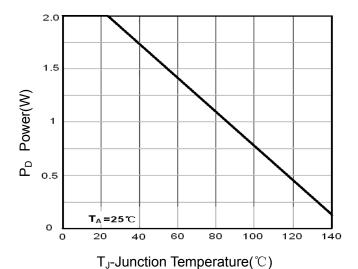


Figure 3 Power Dissipation

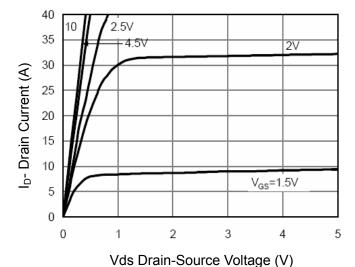


Figure 5 Output Characteristics

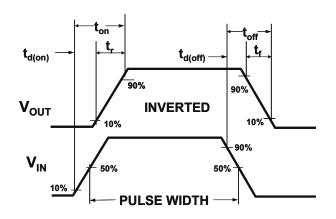


Figure 2:Switching Waveforms

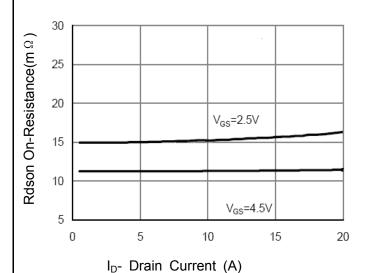


Figure 6 Drain-Source On-Resistance

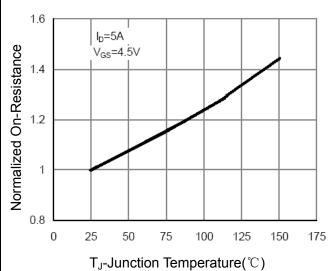
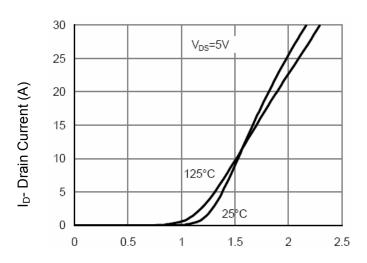


Figure 8 Drain-Source On-Resistance





Vgs Gate-Source Voltage (V)
Figure 7 Transfer Characteristics

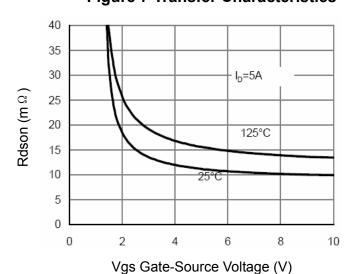
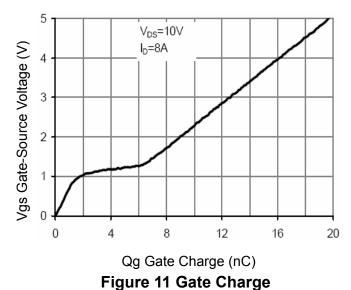


Figure 9 Rdson vs Vgs



3000 2500 2000 1500 1000 C_{rss} 0 5 10 15 20

Vds Drain-Source Voltage (V)

Figure 8 Capacitance vs Vds

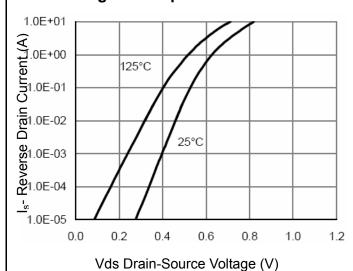


Figure 10Source-DrainDiodeForward

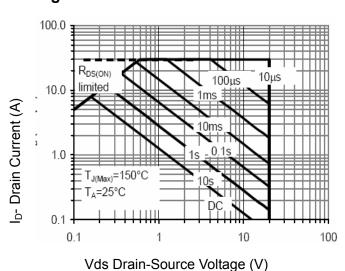


Figure 13 Safe Operation Area



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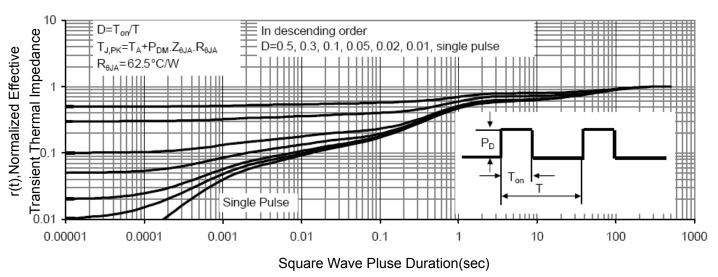
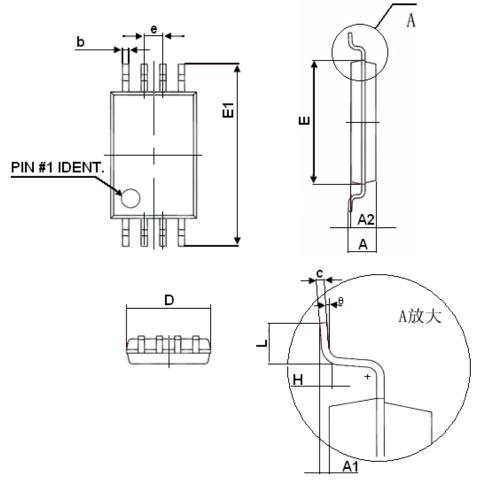


Figure 14 Normalized Maximum Transient Thermal Impedance

Pb Free Product

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Tssop-8 Package Information



Symbol	Dimensions In Millimeters			
Symbol	Min	Max		
D	2.900	3.100		
E	4.300	4.500		
b	0.190	0.300		
С	0.090	0.200		
E1	6.250	6.550		
Α		1.100		
A2	0.800	1.000		
A1	0.020	0.150		
е	0.65(BSC)			
L	0.500	0.700		
Н	0.25(TYP)			
Θ	1°	7°		



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